## NSN 5962-01-068-7841

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View Online at https://aerobasegroup.com/nsn/5962-01-068-7841 **Body Length:** Between 1.188 inches and 1.290 inches **Body Width:** Between 0.515 inches and 0.590 inches **Body Height:** Between 0.100 inches and 0.160 inches **Maximum Power Dissipation Rating:** 650.0 milliwatts **Operating Tempurature Range:** +0.0/+70.0 degrees celsius Storage Tempurature Range: -65.0/+150.0 degrees celsius **Features Provided:** Hermetically sealed and monolithic and positive outputs and w/enable and high speed and schottky and 3-state output **Inclosure Material:** Ceramic and glass **Inclosure Configuration:** Dual-in-line **Output Logic Form:** Transistor-transistor logic **Input Circuit Pattern:** 13 input

**Terminal Surface Treatment:** 

Solder

**Voltage Rating And Type Per Characteristic:** 

5.5 volts power source

**Time Rating Per Chacteristic:** 

70.00 nanoseconds propagation delay time, low to high level output and 70.00 nanoseconds propagation delay time, high to low level output

**Memory Device Type:** 

Rom

**Memory Capacity:** 

Unknown

**Test Data Document:** 

13499-638-2214 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing)

**Terminal Type And Quantity:** 

24 printed circuit

Shelf Life:

N/a

**Unit Of Measure:** 

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**Demilitarization:** 

Yes - demil/mli

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